
HN27C4000G Series

524288-Word × 8-Bit/262144-Word × 16-Bit CMOS UV Erasable
and Programmable ROM

HITACHI

Description

The Hitachi HN27C4000 is a 4-Mbit UV erasable and electrically programmable ROM that is organized either as 524288-word × 8-bit or as 262144-word × 16 bit, featuring extra-high speed burst mode that gives two times faster 4-word or 8-byte serial access than normal. And also high speed and fast programming are served as well as the existing Hitachi 4M device HN27C4096 and HN27C4001. Fabricated on advanced fine process and high speed circuitry technique, HN27C4000 makes high speed access time and low power dissipation in either active or stand-by mode. Therefore, it is suitable for all systems featuring high speed microprocessor such as the 80386, 80486, 68030, 68040 and so on.

Features

- Organization: 524288-word × 8-bit/262144-word × 16-bit ($\overline{\text{BYTE/VPP}}$ enables selection byte-wide or word-wide)
- High speed: Access time 100 ns/120 ns/150 ns (max)
Burst access time 50 ns/60 ns/60 ns (max)
- Low power dissipation:
Standby mode; 5 μW (typ),
Active mode; 150 mW/MHz (typ)
- Fast high reliability page programming, fast high-reliability programming and option programming:
Program voltage; +12.5 V DC
Program time; 3.5 sec (min) (Theoretical in Page programming)
- Inputs and outputs TTL compatible during both read and program modes
- Pin arrangement: 40-pin EIAJ standard pin compatible with HN62414/ HN62434
- Device identifier mode: Manufacturer code and device code

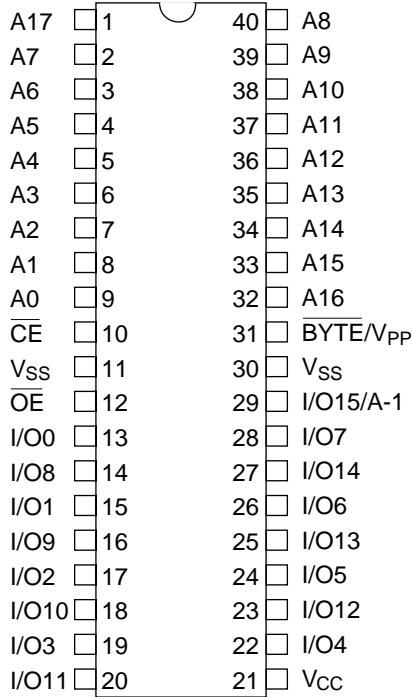
Ordering Information

Type No.	Access Time	Package
HN27C4000G-10	100 ns	600-mil 40-pin cerdip (DG-40A)
HN27C4000G-12	120 ns	
HN27C4000G-15	150 ns	

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Pin Arrangement

HN27C4000G Series

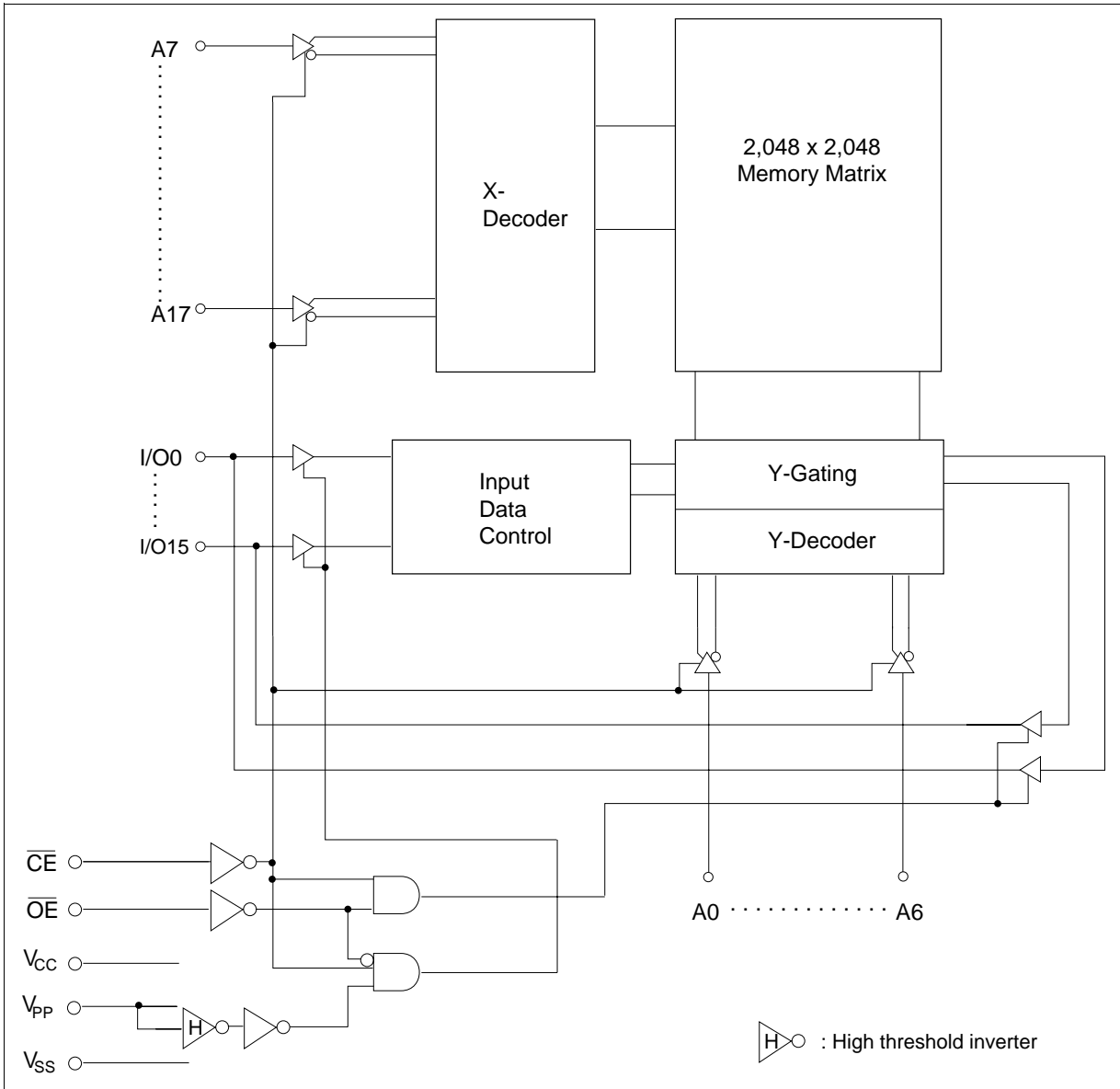


(Top view)

Pin Description

Pin Name	Function
A0 – A17	Address
I/O0 – I/O14	Input/output
I/O15/A-1	Input/output/address
\overline{CE}	Chip enable
\overline{OE}	Output enable
V_{CC}	Power supply
\overline{BYTE}/V_{PP}	Byte/word selection/ Programming power supply
V_{SS}	Ground

Block Diagram



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Mode Selection

Mode	Pin DG-40A	$\overline{\text{CE}}$ (10)	$\overline{\text{OE}}$ (12)	A9 (39)	$\overline{\text{BYTE}}/\text{V}_{\text{PP}}$ (31)	V_{CC} (21)	I/O0 – I/O7, (13 – 20,	I/O8 – I/O14, 22 – 28,	I/O15/ A-1 29)
Read (X16 bit)		V_{IL}	V_{IL}	X	V_{IH}	V_{CC}	Dout	Dout	Dout
Read (X8 bit)		V_{IL}	V_{IL}	X	V_{IL}	V_{CC}	Dout	High-Z	$V_{\text{IH}}/V_{\text{IL}}$
Output disable (X16 bit)		V_{IL}	V_{IH}	X	V_{IH}	V_{CC}	High-Z	High-Z	High-Z
Output disable (X8 bit)		V_{IL}	V_{IH}	X	V_{IL}	V_{CC}	High-Z	High-Z	$V_{\text{IH}}/V_{\text{IL}}$
Standby		V_{IH}	X	X	$V_{\text{SS}} - V_{\text{CC}}$	V_{CC}	High-Z	High-Z	High-Z
Page prog.	Page program set	V_{IH}	V_{H}^{*2}	X	V_{PP}	V_{CC}	High-Z	High-Z	High-Z
	Page data latch	V_{IL}	V_{H}^{*2}	X	V_{PP}	V_{CC}	Din	Din	Din
	Page program	V_{IL}	V_{IH}	X	V_{PP}	V_{CC}	High-Z	High-Z	High-Z
	Page program verify	V_{IH}	V_{IL}	X	V_{PP}	V_{CC}	Dout	Dout	Dout
	Page program reset	V_{IH}	V_{IH}	X	V_{CC}	V_{CC}	High-Z	High-Z	High-Z
Word prog.	Program	V_{IL}	V_{IH}	X	V_{PP}	V_{CC}	Din	Din	Din
	Program verify	V_{IH}	V_{IL}	X	V_{PP}	V_{CC}	Dout	Dout	Dout
	Optional verify	V_{IL}	V_{IL}	X	V_{PP}	V_{CC}	Dout	Dout	Dout
	Program inhibit	V_{IH}	V_{IH}	X	V_{PP}	V_{CC}	High-Z	High-Z	High-Z
Identifier		V_{IL}	V_{IL}	V_{H}^{*2}	$V_{\text{SS}} - V_{\text{CC}}$	V_{CC}	Code	Code	Code

- Notes: 1. X: Don't care.
2. V_{H}^{*2} : 12.0 V \pm 0.5 V

Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
All input and output voltages ¹	$V_{\text{in}}, V_{\text{out}}$	-0.6 ² to +7.0	V
Voltage on pin A9 and $\overline{\text{OE}}$	V_{ID}	-0.6 ² to +13.0	V
V_{PP} voltage ¹	V_{PP}	-0.6 to +13.5	V
V_{CC} voltage ¹	V_{CC}	-0.6 to +7.0	V
Operating temperature range	T_{opr}	0 to +70	°C
Storage temperature range ³	T_{stg}	-65 to +125	°C
Storage temperature under bias	T_{bias}	-20 to +80	°C

- Notes: 1. Relative to V_{SS} .
2. $V_{\text{in}}, V_{\text{out}}, V_{\text{ID}}$ min = -2.0 V for pulse width \leq 20 ns
3. Storage temperature range of device before programming.

Capacitance ($T_a = 25^\circ\text{C}$, $f = 1\text{ MHz}$)

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions	Notes
Input capacitance	Cin	—	—	12	pF	Vin = 0 V	Except $\overline{\text{BYTE}}/V_{PP}$
Output capacitance	Cout	—	—	20	pF	Vout = 0 V	

Read Operation
DC Characteristics ($V_{CC} = 5\text{ V} \pm 10\%$, $V_{PP} = V_{SS}$ to V_{CC} , $T_a = 0$ to $+70^\circ\text{C}$)

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
Input leakage current	I_{LI}	—	—	2	μA	Vin = 5.5 V
Output leakage current	I_{LO}	—	—	2	μA	Vout = 5.5 V/0.45 V
V_{PP} current	I_{PP1}	—	1	20	μA	$V_{PP} = 5.5\text{ V}$
Standby V_{CC} current	I_{SB1}	—	—	1	mA	$\overline{\text{CE}} = V_{IH}$
	I_{SB2}	—	1	20	μA	$\overline{\text{CE}} = V_{CC} \pm 0.3\text{ V}$
Operating V_{CC} current	I_{CC1}	—	—	35	mA	Iout = 0 mA, f = 1 MHz
	I_{CC2}	—	—	120	mA	Iout = 0 mA, f = 10 MHz
Input voltage	V_{IL}	-0.3^{*1}	—	0.8	V	
	V_{IH}	2.2	—	$V_{CC} + 1^{*2}$	V	
Output voltage	V_{OL}	—	—	0.45	V	$I_{OL} = 2.1\text{ mA}$
	V_{OH}	2.4	—	—	V	$I_{OH} = -400\ \mu\text{A}$

Notes: 1. V_{IL} min = -1.0 V for pulse width $\leq 50\text{ ns}$

V_{IL} min = -2.0 V for pulse width $\leq 20\text{ ns}$

2. V_{IH} max = $V_{CC} + 1.5\text{ V}$ for pulse width $\leq 20\text{ ns}$

If V_{IH} is over the specified maximum value, read operation cannot be guaranteed.

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AC Characteristics ($V_{CC} = 5\text{ V} \pm 10\%$, $V_{PP} = V_{SS}$ to V_{CC} , $T_a = 0$ to $+70^\circ\text{C}$)

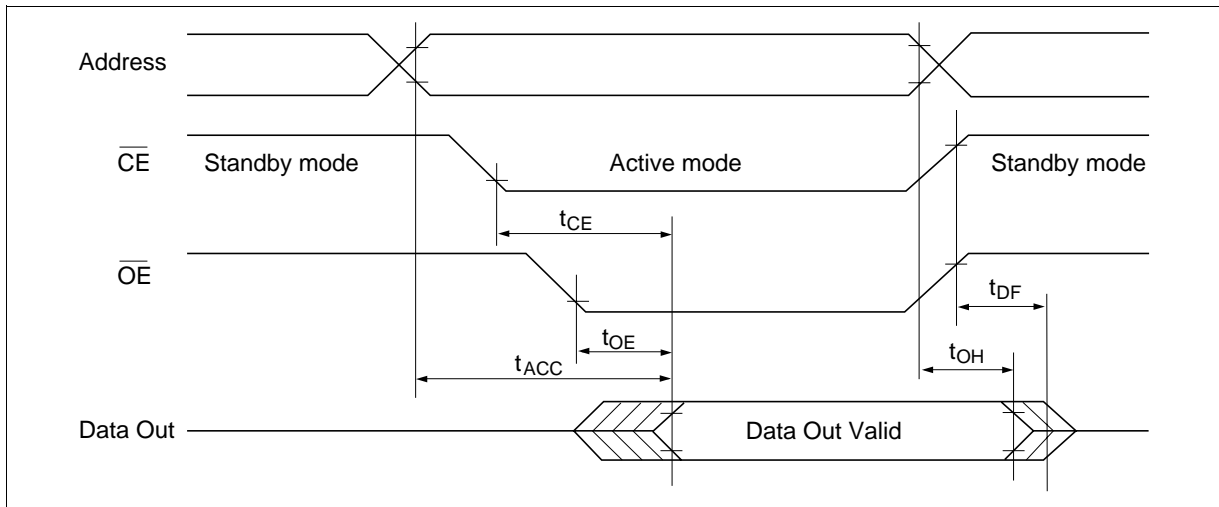
Test Conditions

- Input pulse levels: 0.45 to 2.4 V
- Input rise and fall time: ≤ 10 ns
- Output load: 1 TTL gate +100 pF
- Reference levels for measuring timing: 0.8 V, 2.0 V

		HN27C4000							
		-10		-12		-15			
Parameter	Symbol	Min	Max	Min	Max	Min	Max	Unit	Test Conditions
Address to output delay	t_{ACC}	—	100	—	120	—	150	ns	$\overline{CE} = \overline{OE} = V_{IL}$
\overline{CE} to output delay	t_{CE}	—	100	—	120	—	150	ns	$\overline{OE} = V_{IL}$
\overline{OE} to output delay	t_{OE}	—	60	—	60	—	70	ns	$\overline{CE} = V_{IL}$
Burst address to output delay	t_{BAC}	—	50	—	60	—	60	ns	$\overline{CE} = V_{IL}$
\overline{OE} high to output float ¹	t_{DF}	0	35	0	40	0	50	ns	$\overline{CE} = V_{IL}$
Address to output hold	t_{OH}	5	—	5	—	5	—	ns	$\overline{CE} = \overline{OE} = V_{IL}$

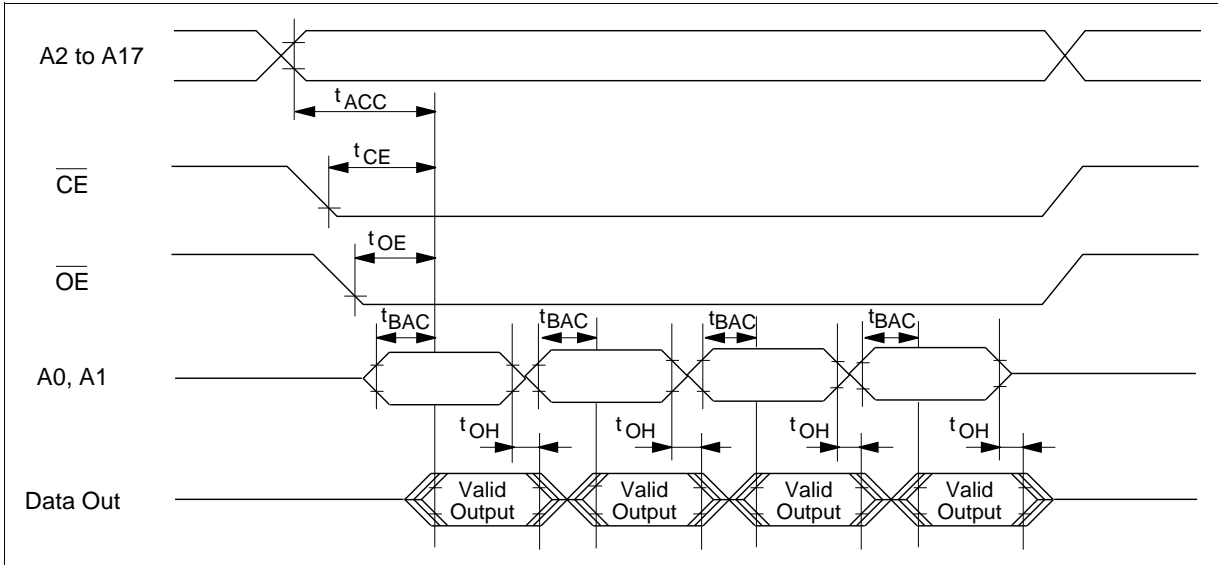
Note: 1. t_{DF} is defined as the time at which the output achieves the open circuit condition and data is no longer driven.

Read Timing Waveform

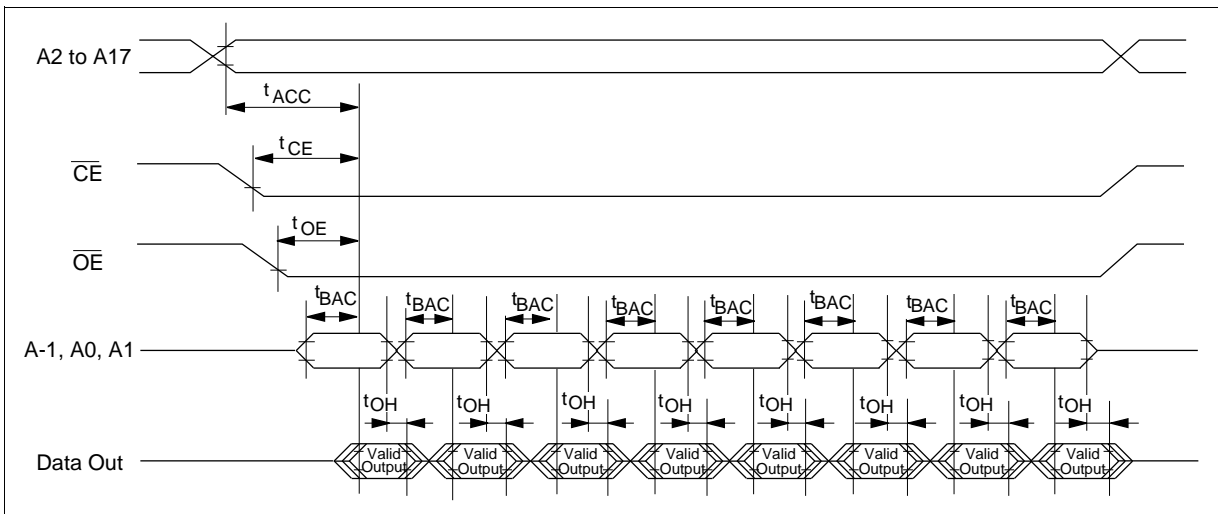


Read Timing Waveform (Burst access mode)

In Burst Access mode, fast read-out of 4 word data is selected by address A0, A1. (Valid only for Read × 16 mode)



In Burst Access mode, fast read-out of 8 byte data is selected by address A-1, A0, A1. (Valid only for Read × 8 mode)



Fast High-Reliability Page Programming

This device can be applied the high performance page programming algorithm shown in the following flowchart. This algorithm allows to obtain faster programming time without any voltage stress to the device nor deterioration in reliability of programmed data.

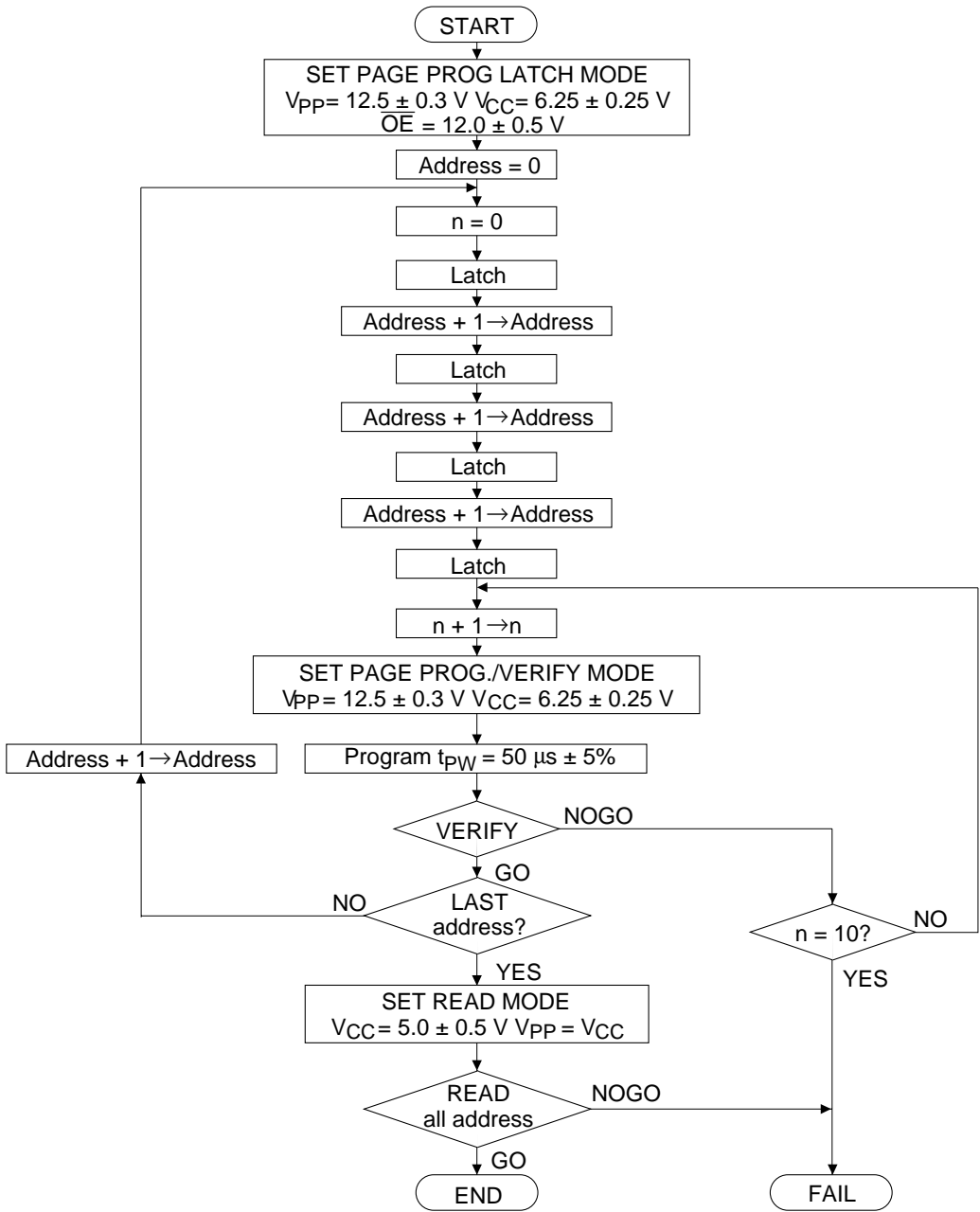
Page Program Set

Apply 12 V to $\overline{\text{OE}}$ pin after applying 12.5 V to V_{pp} to set a page program mode.

The device operates in a page program mode until reset.

Page Program Reset

Set V_{pp} to V_{CC} level or less to reset a page program mode.



Fast High-Reliability Page Programming Flowchart

HN27C4000G Series

DC Characteristics ($V_{CC} = 6.25 \text{ V} \pm 0.25 \text{ V}$, $V_{PP} = 12.5 \text{ V} \pm 0.3 \text{ V}$, $T_a = 25^\circ\text{C} \pm 5^\circ\text{C}$)

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
Input leakage current	I_{LI}	—	—	2	μA	$V_{in} = 6.5 \text{ V}/0.45 \text{ V}$
Output voltage during verify	V_{OL}	—	—	0.45	V	$I_{OL} = 2.1 \text{ mA}$
	V_{OH}	2.4	—	—	V	$I_{OH} = -400 \mu\text{A}$
Operating V_{CC} current	I_{CC}	—	—	50	mA	
Input voltage	V_{IL}	-0.1^{15}	—	0.8	V	
	V_{IH}	2.2	—	$V_{CC} + 0.5^{16}$	V	
	V_H	11.5	12.0	12.5	V	
V_{PP} supply current	I_{PP}	—	—	70	mA	$\overline{CE} = V_{IL}$

- Notes:
1. V_{CC} must be applied simultaneously or before V_{PP} and removed simultaneously or after V_{PP} .
 2. V_{PP} must not exceed 13 V including overshoot.
 3. An influence may be had upon device reliability if the device is installed or removed while $V_{PP} = 12.5 \text{ V}$.
 4. Do not alter V_{PP} either V_{IL} to 12.5 V or 12.5 V to V_{IL} when $\overline{CE} = \text{low}$.
 5. $V_{IL} \text{ min} = -0.6 \text{ V}$ for pulse width $\leq 20 \text{ ns}$.
 6. If V_{IH} is over the specified maximum value, programming operation cannot be guaranteed.

AC Characteristics ($V_{CC} = 6.25 \text{ V} \pm 0.25 \text{ V}$, $V_{PP} = 12.5 \text{ V} \pm 0.3 \text{ V}$, $T_a = 25^\circ\text{C} \pm 5^\circ\text{C}$)

Test Conditions

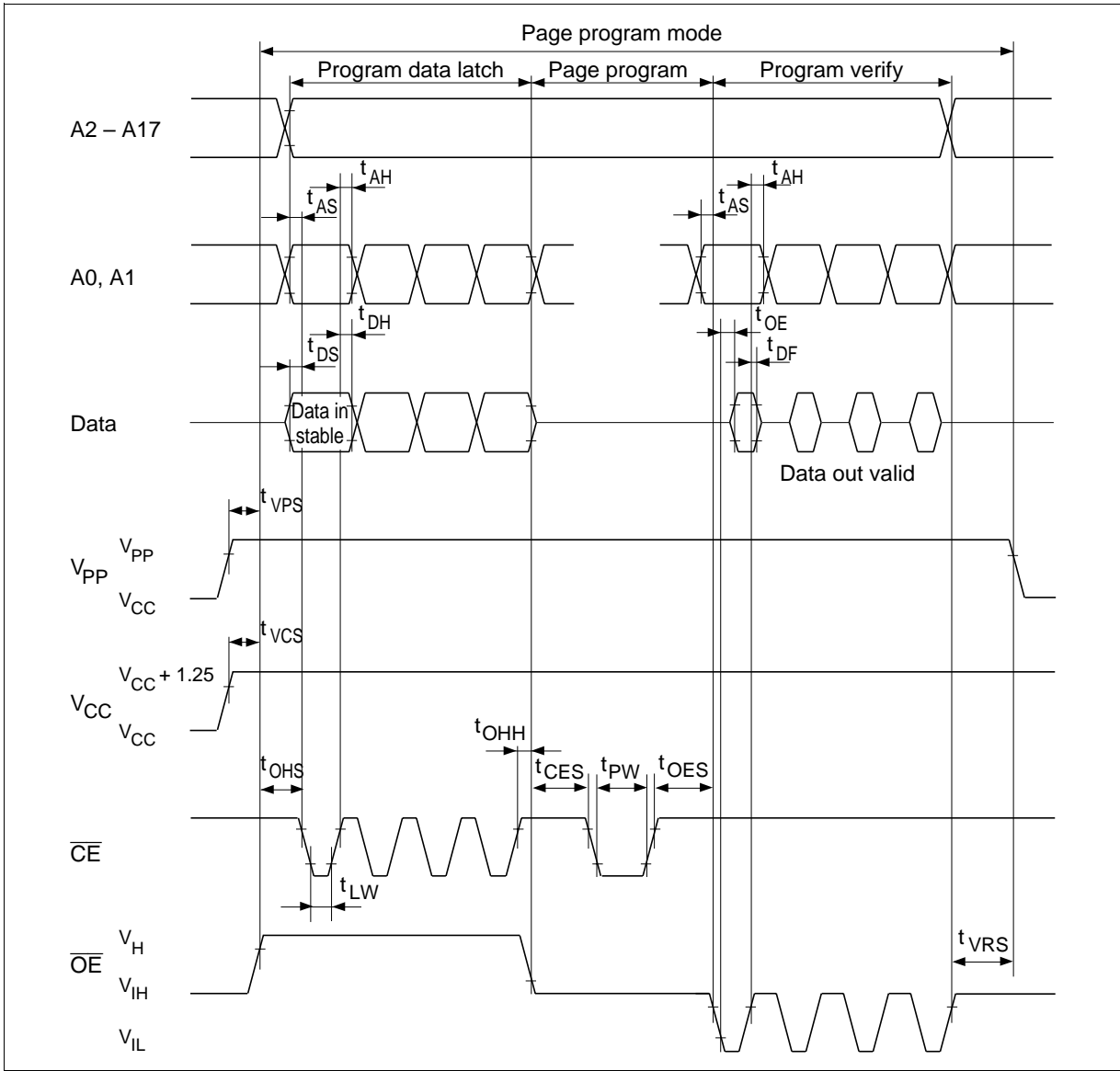
- Input pulse levels: 0.45 to 2.4 V
- Input rise and fall time: $\leq 20 \text{ ns}$
- Reference levels for measuring timing: Inputs; 0.8 V, 2.0 V,
Outputs; 0.8 V, 2.0 V

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
Address setup time	t_{AS}	2	—	—	μs	
\overline{OE} setup time	t_{OES}	2	—	—	μs	
Data setup time	t_{DS}	2	—	—	μs	
Address hold time	t_{AH}	0	—	—	μs	
Data hold time	t_{DH}	2	—	—	μs	
\overline{OE} high to output float delay	t_{DF}^{*1}	0	—	130	ns	
V_{PP} setup time	t_{VPS}	2	—	—	μs	
V_{CC} setup time	t_{VCS}	2	—	—	μs	
\overline{CE} initial programming pulse width	t_{PW}	47.5	50.0	52.5	μs	
\overline{CE} setup time	t_{CES}	2	—	—	μs	
Data valid from \overline{OE}	t_{OE}	0	—	150	ns	
\overline{CE} pulse width during data latch	t_{LW}	1	—	—	μs	
$\overline{OE} = V_H$ setup time	t_{OHS}	2	—	—	μs	
$\overline{OE} = V_H$ hold time	t_{OHH}	2	—	—	μs	
V_{PP} hold time ^{*2}	t_{VRS}	1	—	—	μs	

Notes: 1. t_{DF} is defined as the time at which the output achieves the open circuit condition and data is no longer driven.

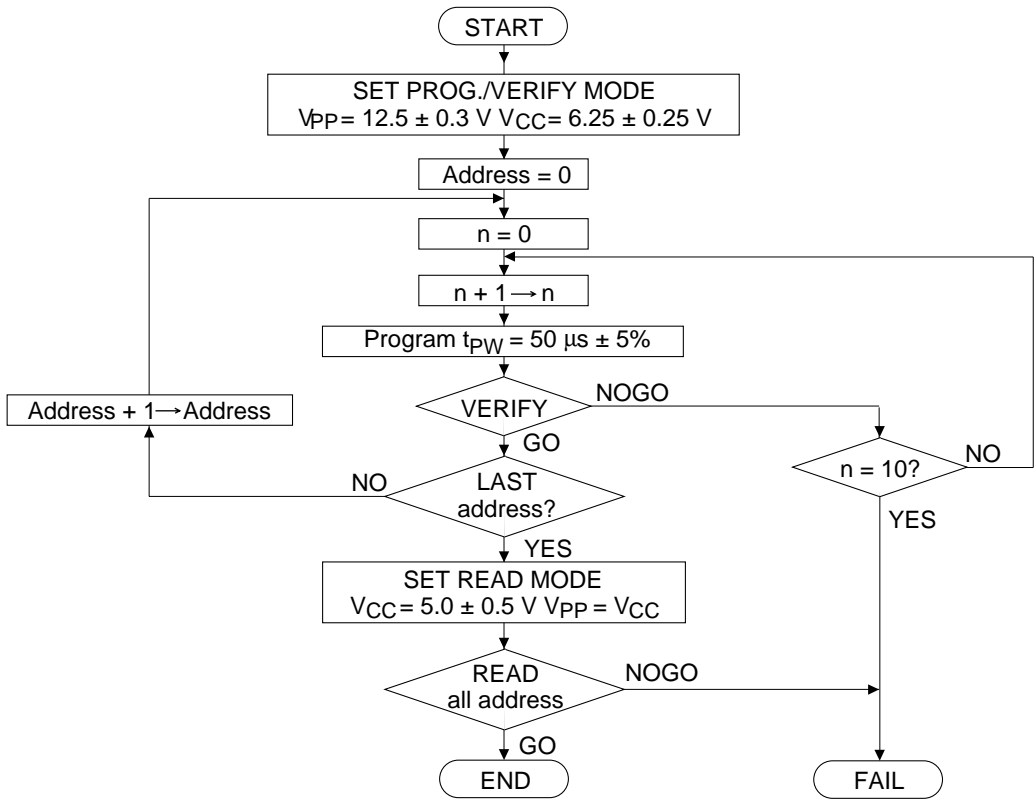
2. Page program mode will be reset when V_{PP} is set to V_{CC} or less.

Fast High-Reliability Page Programming Timing Waveform



Fast High-Reliability Programming

This device can be applied the fast high-reliability programming algorithm shown in the following flowchart. This algorithm allows to obtain faster programming time without any voltage stress to the device nor deterioration in reliability of programmed data.



Fast High-Reliability Programming Flowchart

HN27C4000G Series

DC Characteristics ($V_{CC} = 6.25 \text{ V} \pm 0.25 \text{ V}$, $V_{PP} = 12.5 \text{ V} \pm 0.3 \text{ V}$, $T_a = 25^\circ\text{C} \pm 5^\circ\text{C}$)

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
Input leakage current	I_{LI}	—	—	2	μA	$V_{in} = 6.5 \text{ V}/0.45 \text{ V}$
V_{PP} supply current	I_{PP}	—	—	40	mA	$\overline{CE} = V_{IL}$
Operating V_{CC} current	I_{CC}	—	—	50	mA	
Input voltage	V_{IL}	-0.1^{15}	—	0.8	V	
	V_{IH}	2.2	—	$V_{CC} + 0.5^{16}$	V	
Output voltage	V_{OL}	—	—	0.45	V	$I_{OL} = 2.1 \text{ mA}$
	V_{OH}	2.4	—	—	V	$I_{OH} = -400 \mu\text{A}$

- Notes: 1. V_{CC} must be applied simultaneously or before V_{PP} and removed simultaneously or after V_{PP} .
 2. V_{PP} must not exceed 13 V including overshoot.
 3. An influence may be had upon device reliability if the device is installed or removed while $V_{PP} = 12.5 \text{ V}$.
 4. Do not alter V_{PP} either V_{IL} to 12.5 V or 12.5 V to V_{IL} when $\overline{CE} = \text{low}$.
 5. V_{IL} min = -0.6 V for pulse width $\leq 20 \text{ ns}$.
 6. If V_{IH} is over the specified maximum value, programming operation cannot be guaranteed.

AC Characteristics ($V_{CC} = 6.25 \text{ V} \pm 0.25 \text{ V}$, $V_{PP} = 12.5 \text{ V} \pm 0.3 \text{ V}$, $T_a = 25^\circ\text{C} \pm 5^\circ\text{C}$)

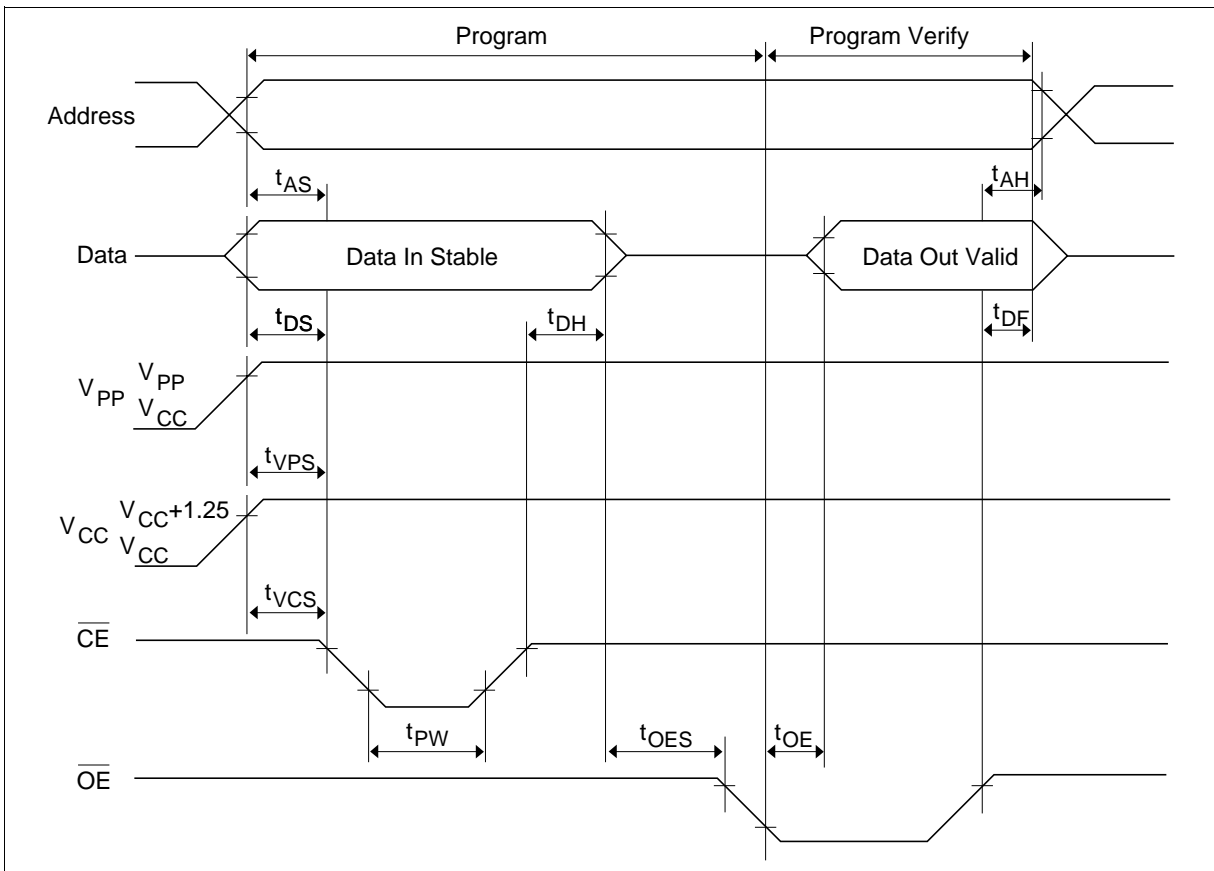
Test Conditions

- Input pulse levels: 0.45 to 2.4 V
- Input rise and fall time: $\leq 20 \text{ ns}$
- Reference levels for measuring timings: 0.8 V, 2.0 V

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
Address setup time	t_{AS}	2	—	—	μs	
\overline{OE} setup time	t_{OES}	2	—	—	μs	
Data setup time	t_{DS}	2	—	—	μs	
Address hold time	t_{AH}	0	—	—	μs	
Data hold time	t_{DH}	2	—	—	μs	
\overline{OE} to output float delay	t_{DF}^{1}	0	—	130	ns	
V_{PP} setup time	t_{VPS}	2	—	—	μs	
V_{CC} setup time	t_{VCS}	2	—	—	μs	
\overline{CE} initial programming pulse width	t_{PW}	47.5	50.0	52.5	μs	
Data valid from \overline{OE}	t_{OE}	0	—	150	ns	

- Note: 1. t_{DF} is defined as the time at which the output achieves the open circuit condition and data is no longer driven.

Fast High-Reliability Programming Timing Waveform

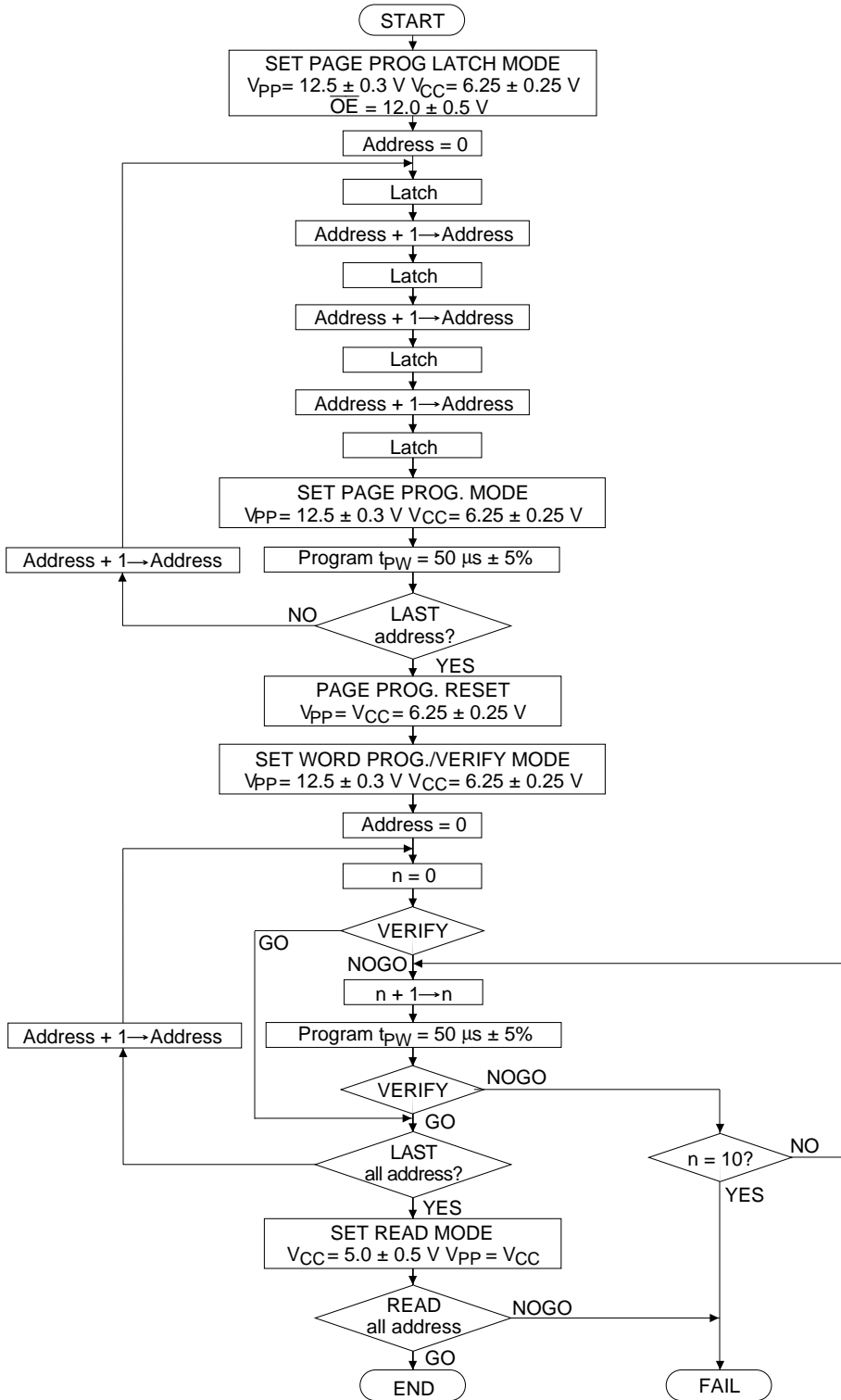


Optional Page Programming

This device can be applied the optional page programming algorithm shown in the following flowchart. This algorithm allows to obtain faster programming time without any voltage stress to the device nor deterioration in reliability of programmed data.

This programming algorithm is the combination of page programming and word verify. It can avoid the increase of programming verify time when a programmer with slow machine cycle is used, and shorten the total programming time.

Regarding the timing specifications for page programming and word verify, please refer to the specifications for fast high-reliability page programming and fast high-reliability programming.



Optional Page Programming Flowchart

DC Characteristics ($V_{CC} = 6.25 \text{ V} \pm 0.25 \text{ V}$, $V_{PP} = 12.5 \text{ V} \pm 0.3 \text{ V}$, $T_a = 25^\circ\text{C} \pm 5^\circ\text{C}$)

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
Input leakage current	I_{LI}	—	—	2	μA	$V_{in} = 6.5 \text{ V}/0.45 \text{ V}$
Output voltage during verify	V_{OL}	—	—	0.45	V	$I_{OL} = 2.1 \text{ mA}$
	V_{OH}	2.4	—	—	V	$I_{OH} = -400 \mu\text{A}$
Operating V_{CC} current	I_{CC}	—	—	50	mA	
Input voltage	V_{IL}	-0.1^{15}	—	0.8	V	
	V_{IH}	2.2	—	$V_{CC} + 0.5^{16}$	V	
	V_H	11.5	12.0	12.5	V	
V_{PP} supply current	I_{PP}	—	—	70	mA	$\overline{CE} = V_{IL}$

- Notes:
- V_{CC} must be applied simultaneously or before V_{PP} and removed simultaneously or after V_{PP} .
 - V_{PP} must not exceed 13 V including overshoot.
 - An influence may be had upon device reliability if the device is installed or removed while $V_{PP} = 12.5 \text{ V}$.
 - Do not alter V_{PP} either V_{IL} to 12.5 V or 12.5 V to V_{IL} when $\overline{CE} = \text{low}$.
 - $V_{IL} \text{ min} = -0.6 \text{ V}$ for pulse width $\leq 20 \text{ ns}$.
 - If V_{IH} is over the specified maximum value, programming operation cannot be guaranteed.

HN27C4000G Series

AC Characteristics ($V_{CC} = 6.25 \text{ V} \pm 0.25 \text{ V}$, $V_{PP} = 12.5 \text{ V} \pm 0.3 \text{ V}$, $T_a = 25^\circ\text{C} \pm 5^\circ\text{C}$)

Test Conditions

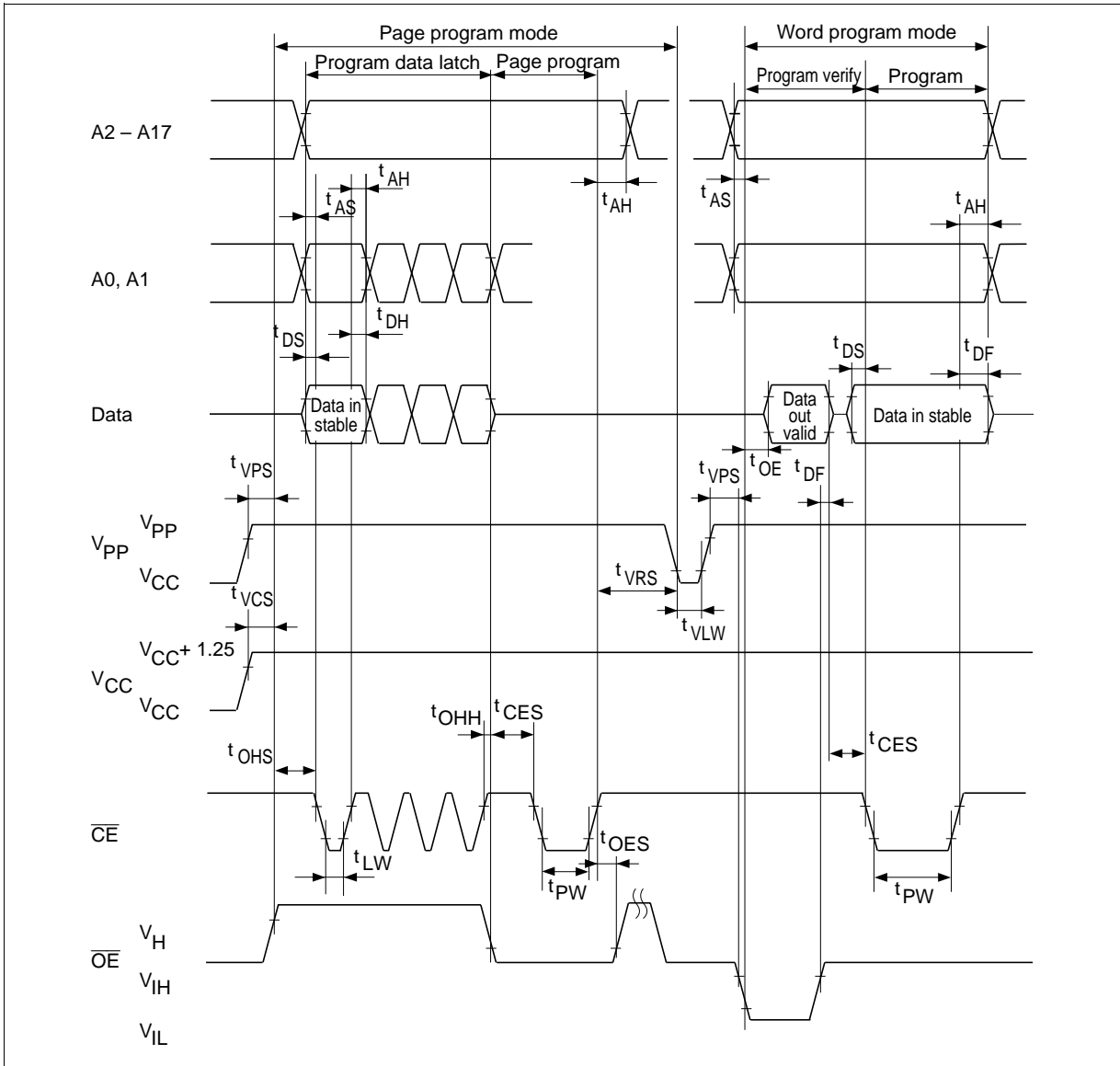
- Input pulse levels: 0.45 to 2.4 V
- Input rise and fall time: $\leq 20 \text{ ns}$
- Reference levels for measuring timings: Inputs; 0.8 V, 2.0 V
Outputs; 0.8 V, 2.0 V

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
Address setup time	t_{AS}	2	—	—	μs	
\overline{OE} setup time	t_{OES}	2	—	—	μs	
Data setup time	t_{DS}	2	—	—	μs	
Address hold time	t_{AH}	0	—	—	μs	
Data hold time	t_{DH}	2	—	—	μs	
\overline{OE} high to output float delay	t_{DF}^{*1}	0	—	130	ns	
V_{PP} setup time	t_{VPS}	2	—	—	μs	
V_{CC} setup time	t_{VCS}	2	—	—	μs	
\overline{CE} initial programming pulse width	t_{PW}	47.5	50.0	52.5	μs	
\overline{CE} setup time	t_{CES}	2	—	—	μs	
Data valid from \overline{OE}	t_{OE}	0	—	150	ns	
\overline{CE} pulse width during data latch	t_{LW}	1	—	—	μs	
$\overline{OE} = V_H$ setup time	t_{OHS}	2	—	—	μs	
$\overline{OE} = V_H$ hold time	t_{OHH}	2	—	—	μs	
Page programming reset time ^{*2}	t_{VLW}	1	—	—	μs	
V_{PP} hold time ^{*2}	t_{VRS}	1	—	—	μs	

Notes: 1. t_{DF} is defined as the time at which the output achieves the open circuit condition and data is no longer driven.

2. Page program mode will be reset when V_{PP} is set to V_{CC} or less.

Option Page Programming Timing Waveform



Erase

Erasure of this device is performed by exposure to ultraviolet light of 2537 Å and all the output data are changed to “1” after this erasure procedure. The minimum integrated dose (i.e. UV intensity X exposure time) for erasure is 15 W · sec/cm².

HN27C4000G Series

Mode Description

Device Identifier Mode

The device identifier mode allows the reading out of binary codes that identify manufacturer and type of device, from outputs of EPROM. By this mode, the device will be automatically matched its own corresponding programming algorithm, using programming equipment.

HN27C4000G Identifier Code

Identifier	DG-40A	A0 (9)	I/O8 – I/O15 —	I/O7 (28)	I/O6 (26)	I/O5 (24)	I/O4 (22)	I/O3 (19)	I/O2 (17)	I/O1 (15)	I/O0 (13)	Hex Data
Manufacturer code		V_{IL}	X	0	0	0	0	0	1	1	1	07
Device code		V_{IH}	X	1	0	1	0	0	0	0	1	A1

- Notes:
1. $V_{CC} = 5.0\text{ V} \pm 10\%$
 2. $A9 = 12.0\text{ V} \pm 0.5\text{ V}$
 3. $\overline{CE}, \overline{OE} = V_{IL}$
 4. A1 – A8, A10 – A17: Don't care.
 5. X: Don't care.

Package Dimensions

HN27C4000G Series (DG-40A)

Unit: mm

